MSA-0686

Cascadable Silicon Bipolar MMIC Amplifier



Data Sheet

Description

The MSA-0686 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50Ω gain block. Applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz f_T , 25 GHz f_{MAX} , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

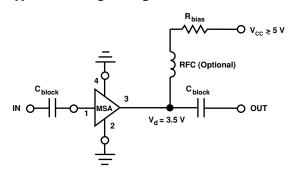
Features

- Cascadable 50Ω Gain Block
- Low Operating Voltage: 3.5 V Typical V_d
- 3 dB Bandwidth: DC to 0.8 GHz
- · High Gain: 18.5 dB Typical at 0.5 GHz
- Low Noise Figure: 3.0 dB Typical at 0.5 GHz
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Available
- · Lead-free Option Available

86 Plastic Package



Typical Biasing Configuration



MSA-0686 Absolute Maximum Ratings

Parameter	Absolute Maximum ^[1]
Device Current	50 mA
Power Dissipation ^[2,3]	200 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	−65 to 150°C

Thermal Resistance ^[2] :	
$\theta_{\rm jc}=120^{\circ}{\rm C/W}$	

Notes

- $1. \ \ Permanent \ damage \ may \ occur \ if \ any \ of \ these \ limits \ are \ exceeded.$
- 2. $T_{CASE} = 25$ °C.
- 3. Derate at 8.3 mW/°C for $T_{\rm C} > 126 ^{\circ}{\rm C}.$

Electrical Specifications^[1], $T_A = 25^{\circ}C$

Symbol	Parameters and Test Conditions:	Units	Min.	Тур.	Max.	
GP	Power Gain $(S_{21} ^2)$	f = 0.1 GHz	dB		20.0	
		f = 0.5 GHz		16.5	18.5	
$\Delta G_{ m P}$	Gain Flatness	f = 0.1 to 0.5 GHz	dB		±0.7	
f _{3 dB}	3 dB Bandwidth		GHz		0.8	
VSWR	Input VSWR	f = 0.1 to 1.5 GHz			1.7:1	
VOVIL	Output VSWR	f = 0.1 to 1.5 GHz			1.7:1	
NF	$50~\Omega$ Noise Figure	f = 0.5 GHz	dB		3.0	
$P_{1 dB}$	Output Power at 1 dB Gain Compression	f = 0.5 GHz	dBm		2.0	
IP_3	Third Order Intercept Point	f = 0.5 GHz	dBm		14.5	
t_{D}	Group Delay	f = 0.5 GHz	psec		225	
Vd	Device Voltage		V	2.8	3.5	4.2
dV/dT	Device Voltage Temperature Coefficient		mV/°C		-8.0	

Notes:

Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0686-BLK	100	Bulk
MSA-0686-BLKG	100	Bulk
MSA-0686-TR1	1000	7" Reel
MSA-0686-TR1G	1000	7" Reel
MSA-0686-TR2	4000	13" Reel
MSA-0686-TR2G	1000	13" Reel

Note: Order part number with a "G" suffix if lead-free option is desired.

^{1.} The recommended operating current range for this device is 12 to 20 mA. Typical performance as a function of current is on the following page.

MSA-0686 Typical Scattering Parameters ($Z_0 = 50 \Omega$, $T_A = 25^{\circ}$ C, $I_d = 16 \text{ m/s}$	MSA-	·0686 Typical	Scattering	Parameters	$(Z_0 = 5)$	$50\ \Omega$, T_{A}	$= 25^{\circ}$ C,	$I_{\rm d} = 16 {\rm m}$
---	------	---------------	------------	-------------------	-------------	------------------------	-------------------	---------------------------

Freq.	\mathbf{S}_1	1		S_{21}		\mathbf{S}_{12}					
GHz	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang	k
0.1	.06	-175	20.1	10.08	170	-23.3	.069	4	.04	-84	1.05
0.2	.06	-169	19.8	9.77	161	-23.2	.069	8	.07	-103	1.05
0.3	.07	-164	19.4	9.35	152	-22.5	.075	13	.10	-113	1.03
0.4	.08	-158	19.1	8.98	144	-22.2	.078	16	.13	-123	1.02
0.5	.08	-154	18.7	8.58	135	-21.6	.083	18	.15	-131	1.01
0.6	.09	-152	18.0	7.94	128	-21.1	.088	21	.18	-140	1.01
0.8	.12	-152	17.2	7.25	114	-20.3	.097	25	.21	-155	1.00
1.0	.15	-154	16.3	6.51	102	-19.5	.106	25	.24	-168	0.99
1.5	.25	-171	14.0	5.01	76	-17.6	.133	22	.27	165	0.99
2.0	.34	171	11.9	3.94	56	-16.1	.157	19	.27	147	1.01
2.5	.43	155	9.8	3.09	42	-15.9	.161	16	.27	134	1.06
3.0	.49	140	8.0	2.51	28	-15.3	.171	11	.26	124	1.10
3.5	.56	128	6.4	2.09	15	-15.1	.175	6	.25	118	1.13
4.0	.61	118	5.0	1.78	3	-14.9	.180	3	.24	115	1.15
5.0	.70	99	2.4	1.32	-18	-14.7	.185	-2	.24	118	1.16

Typical Performance, $T_A = 25^{\circ}C$

(unless otherwise noted)

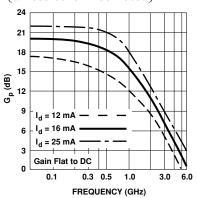


Figure 1. Typical Power Gain vs. Frequency, $T_A=25^{\circ}\mathrm{C}.$

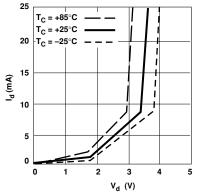


Figure 2. Device Current vs. Voltage.

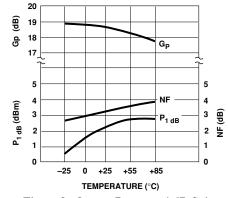


Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature, f = 1.0 GHz, I_d = 16 mA.

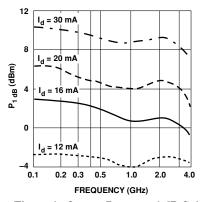


Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.

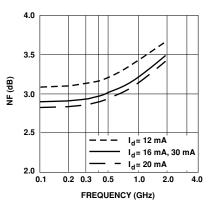
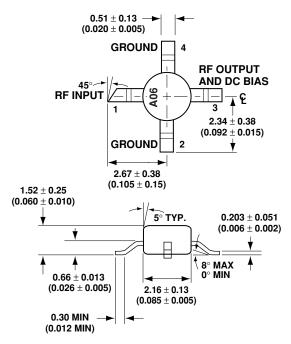


Figure 5. Noise Figure vs. Frequency.

86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)

For product information and a complete list of distributors, please go to our web site: **www.avagotech.com**

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies, Limited in the United States and other countries.

Data subject to change. Copyright © 2006 Avago Technologies, Limited. All rights reserved. Obsoletes 5965-9588EN

5989-2757EN May 11, 2006

